





Product Summary

Continuous Drain Source Voltage: V_{DS} = 60V

On-State Resistance: 550mΩ

Nominal Load Current (V_{IN} = 5V): 1.4A

Clamping Energy: 550mJ

Description

The BSP75G is a self-protected low-side MOSFET. It features monolithic over temperature, over current, over voltage (active clamp) and ESD protected logic level functionality. It is intended as a general purpose switch.

Applications

- Especially Suited for Loads with a High In-Rush Current such as Lamps and Motors
- All Types of Resistive, Inductive and Capacitive Loads in Switching Applications
- µC Compatible Power Switch for 12V and 24V DC Applications
- Automotive Rated
- Replaces Electromechanical Relays and Discrete Circuits
- Linear Mode Capability the current-limiting protection circuitry is
 designed to de-activate at low V_{DS} to in order not to compromise
 the load current during normal operation. The maximum DC
 operating current is therefore determined by the thermal
 capability of the package/board combination, rather than by the
 protection circuitry.

Features and Benefits

- Short Circuit Protection with Auto Restart
- Over Voltage Protection (Active Clamp)
- Thermal Shutdown with Auto Restart
- Over-Current Protection
- Input Protection (ESD)
- Load Dump Protection (Actively Protects Load)
- Logic Level Input
- High Continuous Current Rating
- Lead-Free Finish; RoHS Compliant (Note 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- An Automotive-Compliant Part is Available Under Separate Datasheet (BSP75GQ)

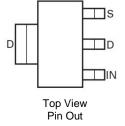
Mechanical Data

- Case: SOT223 (Type DN)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish (a)
- Weight: 0.112 grams (Approximate)

SOT223 (Type DN)



Top View



Note: The tab is connected to the drain pin, and must be electrically isolated from the source pin. Connection of significant copper to the tab is recommended for best thermal performance.

Ordering Information (Note 4)

Product	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
BSP75GTA	BSP75G	7	12	1,000 Units
BSP75GTC	BSP75G	13	12	4,000 Units

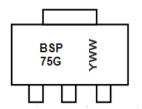
Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead_free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

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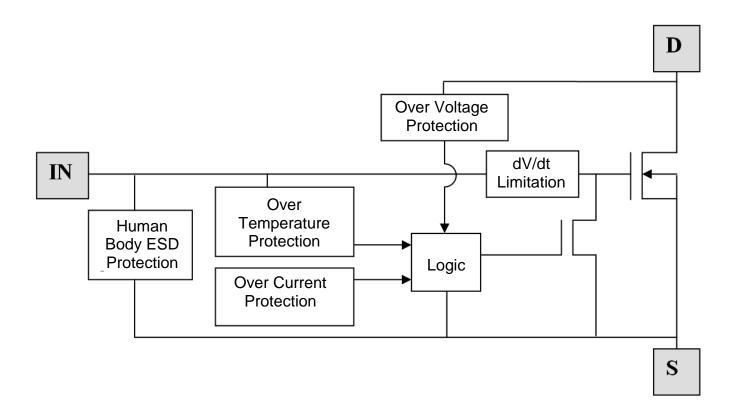


Marking Information



BSP75G = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 8 = 2018) WW or \overline{WW} = Week Code (01 to 53)

Functional Block Diagram





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise stated.)

Parameter	Symbol	Limit	Unit
Continuous Drain-Source Voltage	V _{DS}	60	V
Drain-Source Voltage for Short Circuit Protection V _{IN} = 5V	V _{DS(SC)}	36	V
Continuous Input Voltage	V _{IN}	-0.2 to +10	V
Peak Input Voltage	V _{IN}	-0.2 to +20	V
Operating Temperature Range	TJ	-40 to +150	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C
Power Dissipation at T _A = +25°C (Note 5)	P _D	2.5	W
Continuous Drain Current @ V _{IN} =10V; T _A = +25°C (Note 5)	I _D	1.6	Α
Continuous Drain Current @ V _{IN} =5V; T _A = +25°C (Note 5)	I _D	1.4	Α
Pulsed Drain Current @ V _{IN} = 10V	I _{DM}	5	Α
Continuous Source Current (Body Diode) (Note 5)	Is	3	Α
Pulsed Source Current (Body Diode)	Is	5	Α
Unclamped Single Pulse Inductive Energy	E _{AS}	550	mJ
Load Dump Protection	VLOAD_DUMP	80	V
Electrostatic Discharge (Human Body Model)	V _{ESD}	4000	V
DIN Humidity Category, DIN 40 040	_	Е	_
IEC Climatic Category, DIN IEC 68-1	_	40/150/56	_

Thermal Resistance

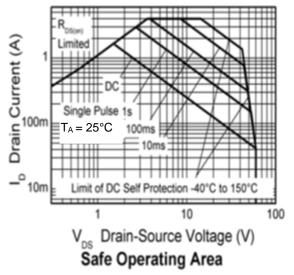
Characteristic	Symbol	Limit	Unit
Junction to Ambient (Note 5)	$R_{\theta JA}$	50	°C/W
Junction to Ambient (Note 6)	R _{0JA}	24	°C/W
Junction to Ambient (Note 7)	R _{θJA}	208	°C/W

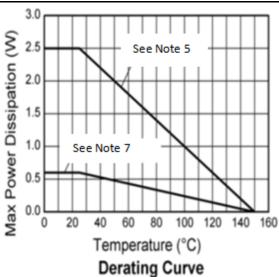
Notes:

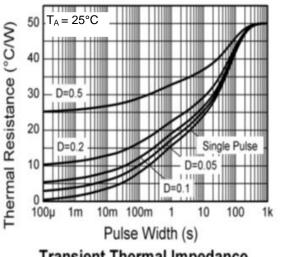
- 5. For a device surface mounted on 37mm x 37mm x 1.6mm FR-4 board with a high coverage of single sided 2oz weight copper.
- 6. For a device surface mounted on FR-4 board and measured at $t \le 10$ s.
- 7. For a device mounted on FR-4 board with the minimum copper required for electrical connections.

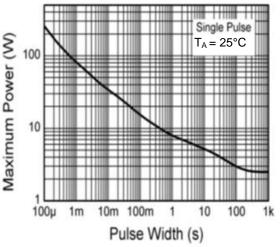


Typical Characteristics









Transient Thermal Impedance

Pulse Power Dissipation



Electrical Characteristics (@T_A = +25°C, unless otherwise stated.)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Static Characteristics	Static Characteristics					
Drain-Source Clamp Voltage	$V_{DS(AZ)}$	60	70	75	V	I _D =10mA
Off state Drain Current	I _{DSS}	_	0.1	3	μA	V _{DS} =12V, V _{IN} =0V
Off state Drain Current	I _{DSS}	_	3	15	μA	V _{DS} =32V, V _{IN} =0V
Input Threshold Voltage (Note 8)	$V_{IN(TH)}$	1	2.1	1	V	V _{DS} =V _{GS} , I _D =1mA
Input Current	I _{IN}	_	0.7	1.2	mA	V _{IN} =5V
Input Current	I _{IN}	_	1.5	2.7	mA	V _{IN} =7V
Input Current	I _{IN}	_	4	7	mA	V _{IN} =10V
Static Drain-Source On-State Resistance	R _{DS(ON)}	_	520	675	mΩ	V _{IN} =5V, I _D =0.7A
Static Drain-Source On-State Resistance	R _{DS(ON)}	_	385	550	mΩ	V _{IN} =10V, I _D =0.7A
Current Limit (Note 9)	I _{D(LIM)}	0.7	1.1	1.75	Α	V _{IN} =5V, V _{DS} >5V
Current Limit (Note 9)	I _{D(LIM)}	2	3	4	А	V _{IN} =10V, V _{DS} >5V
Dynamic Characteristics						
Turn-On Time (V _{IN} to 90% I _D)	ton	-	2.2	1	μs	R_L =22 Ω , V_{IN} =0 to 10V, V_{DD} =12V
Turn-Off Time (V _{IN} to 90% I _D)	toff	-	13	1	μs	R_L =22 Ω , V_{IN} =10V to 0V, V_{DD} =12V
Slew Rate On (70 to 50% V _{DD})	$-dV_{DS}/dt_{ON}$	_	10		V/µs	R_L =22 Ω , V_{IN} =0 to 10V, V_{DD} =12V
Slew Rate Off (50 to 70% V _{DD})	dV_{DS}/dt_{ON}	_	3.2	ı	V/µs	R_L =22 Ω , V_{IN} =10V to 0V, V_{DD} =12V
Protection Functions (Note 10)	Protection Functions (Note 10)					
Minimum Input Voltage for Over Temperature Protection	V_{PROT}	4.5	_	_	V	_
Thermal Overload Trip Temperature	T_{JT}	+150	+175	_	°C	_
Thermal Hysteresis	_	_	+10	_	°C	_
Unclamped Single Pulse Inductive Energy T _J = +25°C	E _{AS}	550	_	-	mJ	I _{D(ISO)} =0.7A, V _{DD} =32V
Unclamped Single Pulse Inductive Energy T _J = +150°C	E _{AS}	200	_	_	mJ	I _{D(ISO)} =0.7A, V _{DD} =32V
Inverse Diode						
Source Drain Voltage	V _{SD}	_	_	1	V	V _{IN} =0V, -I _D =1.4A

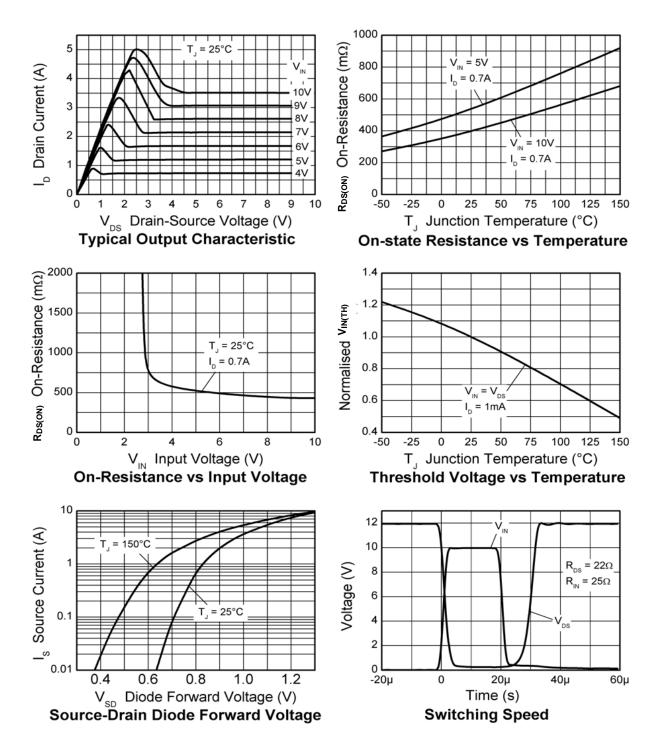
Notes:

^{8.} Protection features may operate outside spec for V_{IN} < 4.5V.

 ^{9.} The drain current is limited to a reduced value when V_{DS} exceeds a safe level.
 10. Integrated protection functions are designed to prevent IC destruction under fault conditions described in the datasheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous, repetitive operation.



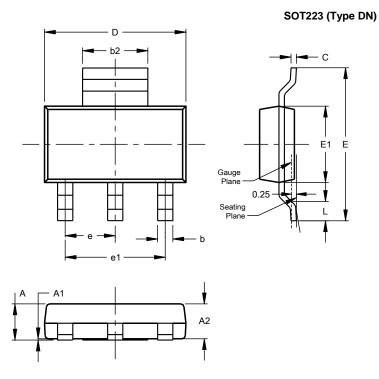
Characteristics





Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

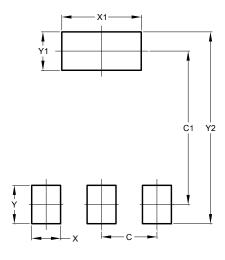


SOT223 (Type DN)				
Dim	Min	Max	Тур	
Α		1.70		
A1	0.01	0.15		
A2	1.50	1.68	1.60	
b	0.60	0.80	0.70	
b2	2.90	3.10		
С	0.20	0.32		
D	6.30	6.70		
Е	6.70	7.30		
E1	3.30	3.70		
е			2.30	
e1			4.60	
L	0.85			
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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